Vishay Semiconductors

High Performance Schottky Rectifier, 100 A



PowerTab[®]

LINKS TO ADDITIONAL RESOURCES



| PRIMARY CHARACTERISTICS | | | | | | |
|----------------------------------|-----------------------|--|--|--|--|--|
| I _{F(AV)} 100 A | | | | | | |
| V _R | 30 V | | | | | |
| V _F at I _F | 0.56 V | | | | | |
| I _{RM} | 460 mA at 125 °C | | | | | |
| T _J max. | 150 °C | | | | | |
| E _{AS} | 36 mJ | | | | | |
| Package | PowerTab [®] | | | | | |
| Circuit configuration | Single | | | | | |

FEATURES

- 150 °C max. operating junction temperature
- High frequency operation
- Ultralow forward voltage drop
- Continuous high current operation
- Guard ring for enhanced ruggedness and long term reliability
- Screw mounting only
- AEC-Q101 qualified
- PowerTab[®] package
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-100BGQ030HN4 Schottky rectifier has been optimized for ultralow forward voltage drop specifically for low voltage output in high current AC/DC power supplies. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MECHANICAL DATA

Case: PowerTab®

Molding compound meets UL 94 V-0 flammability rating **Terminal:** nickel plated, screwable

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | | |
|-----------------------------------|----------------------------------|-------------|----|--|--|--|--|
| SYMBOL | SYMBOL CHARACTERISTICS VALUES UN | | | | | | |
| 1 | Rectangular waveform | 100 | А | | | | |
| IF(AV) | T _C | 106 | °C | | | | |
| V _{RRM} | | 30 | V | | | | |
| I _{FSM} | t _p = 5 μs sine | 4500 | A | | | | |
| N | 100 A _{pk} (typical) | 0.49 | V | | | | |
| V _F | TJ | 150 | °C | | | | |
| Тյ | Range | -55 to +150 | °C | | | | |

| VOLTAGE RATINGS | | | | | |
|--------------------------------------|------------------|-----------------|-------|--|--|
| PARAMETER | SYMBOL | VS-100BGQ030HF4 | UNITS | | |
| Maximum DC reverse voltage | V _R | 30 | M | | |
| Maximum working peak reverse voltage | V _{RWM} | 30 | v | | |

| ABSOLUTE MAXIMUM RATINGS | | | | | | |
|--|--------------------|---|--------------------------|-------|----|--|
| PARAMETER | SYMBOL | TEST COND | VALUES | UNITS | | |
| Maximum average forward current | I _{F(AV)} | 50 % duty cycle at T_C = 106 °C, rectangular waveform | | 100 | А | |
| Maximum peak one cycle non-repetitive surge current | | 5 µs sine or 3 µs rect. pulse | Following any rated load | 4500 | | |
| | | 10 ms sine or 6 ms rect. pulse Condition and with rated V _{RRM} applied | | 850 | A | |
| Non-repetitive avalanche energy | E _{AS} | T _J = 25 °C, I _{AS} = 8 A, L = 1.12 mH | | 36 | mJ | |
| Repetitive avalanche current | I _{AR} | $\begin{array}{c} \mbox{Current decaying linearly to zero in 1 } \mu s \\ \mbox{Frequency limited by } T_J \mbox{maximum } V_A = 1.5 \ x \ V_B \ typical \end{array} 8$ | | А | | |

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ROHS COMPLIANT HALOGEN







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| ELECTRICAL SPECIFICATIONS | | | | | | | |
|--------------------------------|--------------------------------|--|---------------------------------------|------|------|-------|--|
| PARAMETER | SYMBOL | TEST CO | NDITIONS | TYP. | MAX. | UNITS | |
| | | 50 A | T.I = 25 °C | 0.47 | 0.5 | V | |
| Forward voltage drop | V _{EM} ⁽¹⁾ | 100 A | 1j=25 0 | 0.56 | 0.63 | | |
| rorward voltage drop | VFM (*) | 50 A | T,I = 150 °C | 0.36 | 0.4 | | |
| | | 100 A | 1j = 150 C | 0.49 | 0.56 | | |
| | I _{RM} ⁽¹⁾ | T _J = 125 °C | 80 | 160 | | | |
| Reverse leakage current | | T _J = 150 °C | 840 | 1350 | | | |
| neverse leakage current | | T _J = 25 °C | $V_{\rm B} = Rated V_{\rm B}$ | 0.6 | 2.4 | - mA | |
| | | T _J = 125 °C | V _R = naleu V _R | 260 | 460 | | |
| Maximum junction capacitance | CT | V_{R} = 5 V_{DC} , (test signal range 100 kHz to 1 MHz) 25 °C 3800 | | | pF | | |
| Typical series inductance | L _S | Measured from tab to mounting plane 3.5 | | | nH | | |
| Maximum voltage rate of change | dV/dt | Rated V _R 10 000 V. | | | V/µs | | |

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | |
|--|---------|-----------------------------------|--------------------------------------|-------------|------------|--|
| PARAMETER | | SYMBOL | TEST CONDITIONS | VALUES | UNITS | |
| Maximum junction and storage temperature range | | T _J , T _{Stg} | | -55 to +150 | °C | |
| Maximum thermal resistance, junction to case | | R _{thJC} | DC operation 0.5 | | °C/W | |
| Typical thermal resistance, case to heatsink | | R _{thCS} | Mounting surface, smooth and greased | 0.30 | C/W | |
| Approximate weight | | | | 5 | g | |
| Mounting torque | minimum | | | 1.2 (10) | N·m | |
| maximu | | | | 2.4 (20) | (lbf · in) | |
| Marking device Case style PowerTab [®] 100B | | 100BG | Q030H | | | |

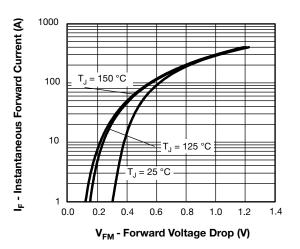
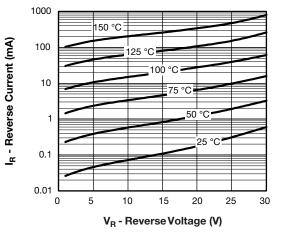
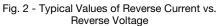


Fig. 1 - Maximum Forward Voltage Drop Characteristics





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VS-100BGQ030HN4

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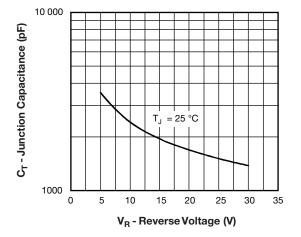


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

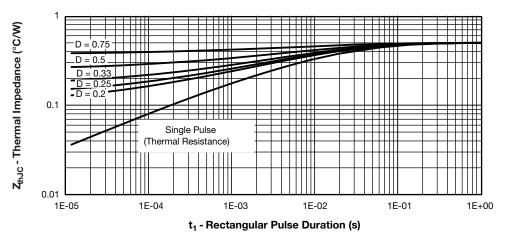
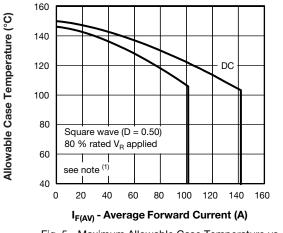
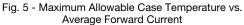
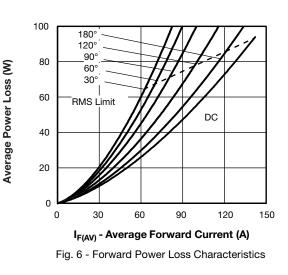


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics







Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mbox{Pd} = \mbox{Forward power loss} = \mbox{I}_{F(AV)} \times \mbox{V}_{FM} \mbox{ at } (\mbox{I}_{F(AV)}/D) \mbox{ (see fig. 6);} \\ \mbox{Pd}_{REV} = \mbox{Inverse power loss} = \mbox{V}_{R1} \times \mbox{I}_{R} \mbox{ (1 - D); } \mbox{I}_{R} \mbox{ at } \mbox{V}_{R1} = 80 \ \% \mbox{ rated } \mbox{V}_{R} \end{array}$

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VS-100BGQ030HN4 Vishay Semiconductors

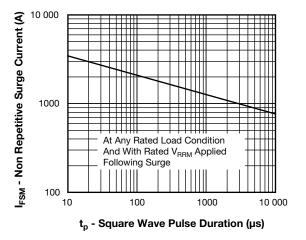
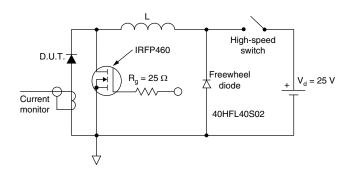
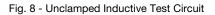


Fig. 7 - Maximum Non-Repetitive Surge Current





ORDERING INFORMATION TABLE

| Device code | VS- | 100 | BGQ | 030 | н | N4 |
|-------------|---------------------------|------------|-----------|------------|------------|------------|
| | | 2 | (3) | (4) | (5) | 6 |
| | | \bigcirc | hav Sem | \bigcirc | \bigcirc | \bigcirc |
| | 2 - | | rent rati | | | |
| | 3 - Essential part number | | | | | |
| | 4 - | Vol | tage rati | ng (030 | = 30 V) | |
| | 5 - | H= | AEC-Q | 101 qua | lified | |
| | 6 - | En | /ironmer | ntal digit | : | |
| | - | N4 | = Halog | en-free, | RoHS o | compliar |

| ORDERING INFORMATION (Example) | | | | | |
|---|---------|-------------------------|--|--|--|
| PREFERRED P/N BASE QUANTITY PACKAGING DESCRIPTION | | | | | |
| VS-100BGQ030HN4 | 25/tube | Antistatic plastic tube | | | |

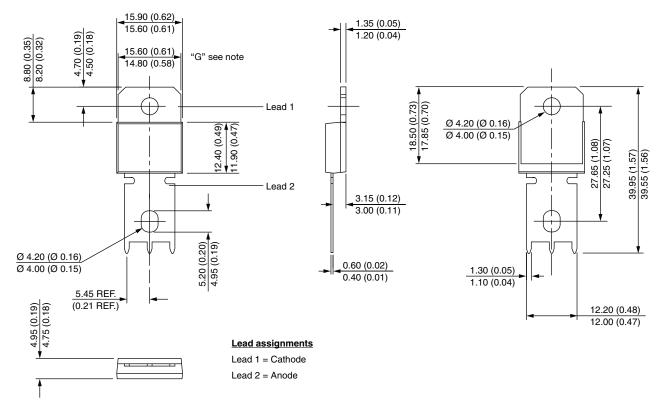
| LINKS TO RELATED DOCUMENTS | | | | | | |
|-------------------------------------|--------------------------|--|--|--|--|--|
| Dimensions www.vishay.com/doc?95240 | | | | | | |
| Part marking information | www.vishay.com/doc?95467 | | | | | |
| Application note | www.vishay.com/doc?95179 | | | | | |



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PowerTab[®]

DIMENSIONS in millimeters (inches)



Note:

Outline conform to JEDEC® TO-275, except for dimension "G" only



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